2SA1507/2SC3902



Bipolar Transistor

(-)160V, (-)1.5A, Low VCE(sat), (PNP)NPN Single TO-126ML

http://onsemi.com

Applications

· Color TV audio output, converters, inverters

Features

- · High breakdown voltage
- · Large current capacity
- · Adoption of FBET and MBIT process
- The plastic-covered heat sink eliminates the need for an insulator when mounting the 2SA1507/2SC3902

Specifications (): 2SA1507

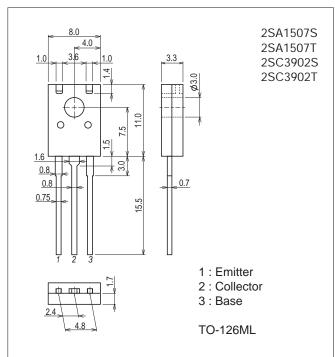
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)180	V
Collector-to-Emitter Voltage	VCEO		(-)160	V
Emitter-to-Base Voltage	V _{EBO}		(–)6	V
Collector Current	IC		(-)1.5	А
Collector Current (Pulse)	ICP		(-)2.5	Α
Collector Dissipation	Do		1.5	W
	PC	Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

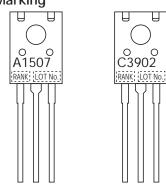
unit : mm (typ) 7516A-002



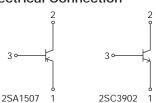
Product & Package Information

Package : TO-126ML
 JEITA, JEDEC : TO-126
 Minimum Packing Quantity : 200 pcs./bag

Marking



Electrical Connection



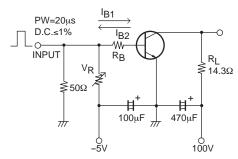
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Parameter	Syllibol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)120V, I _E =0A			(-)1.0	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0A			(-)1.0	μА
DC Current Gain	h _{FE} 1	V _{CE} =(-)5V, I _C =(-)100mA	100*		400*	
	h _{FE} 2	V _{CE} =(-)5V, I _C =(-)10mA	90			
Gain-Bandwidth Product	fŢ	V _{CE} =(-)10V, I _C =(-)50mA		120		MHz
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		(22)14		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C =(-)500mA, I _B =(-)50mA		(-0.2)0.13	(-0.5)0.45	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =(-)500mA, I _B =(-)50mA		(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=(-)10μA, IE=0A	(-)180			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=(-)1mA, RBE=∞	(-)160			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)10μA, I _C =0A	(-)6			V
Turn-On Time	ton			(0.7)0.04		μS
Storage Time	t _{stg}	See specified Test Circuit.		(0.7)1.2		μS
Fall Time	tf			(0.04)0.08		μS

* : The 2SA1507 / 2SC3902 are classified by 100mA hFE as follows:

Rank	R	S	T	
$h_{ ext{FE}}$	100 to 200	140 to 280	200 to 400	

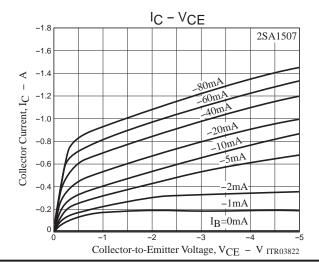
Switching Time Test Circuit

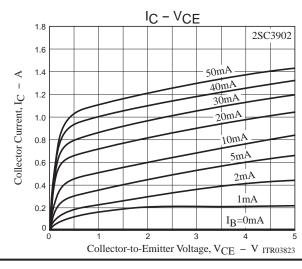


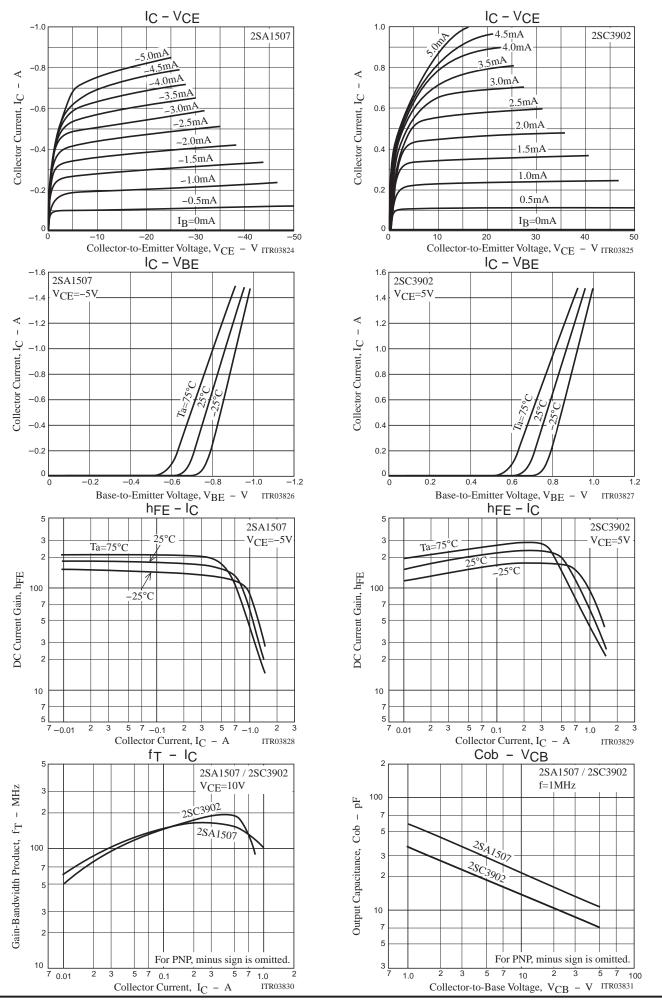
 $I_{C} = 10I_{B1} = -10I_{B2} = 0.7A$ (For PNP, the polarity is reversed.)

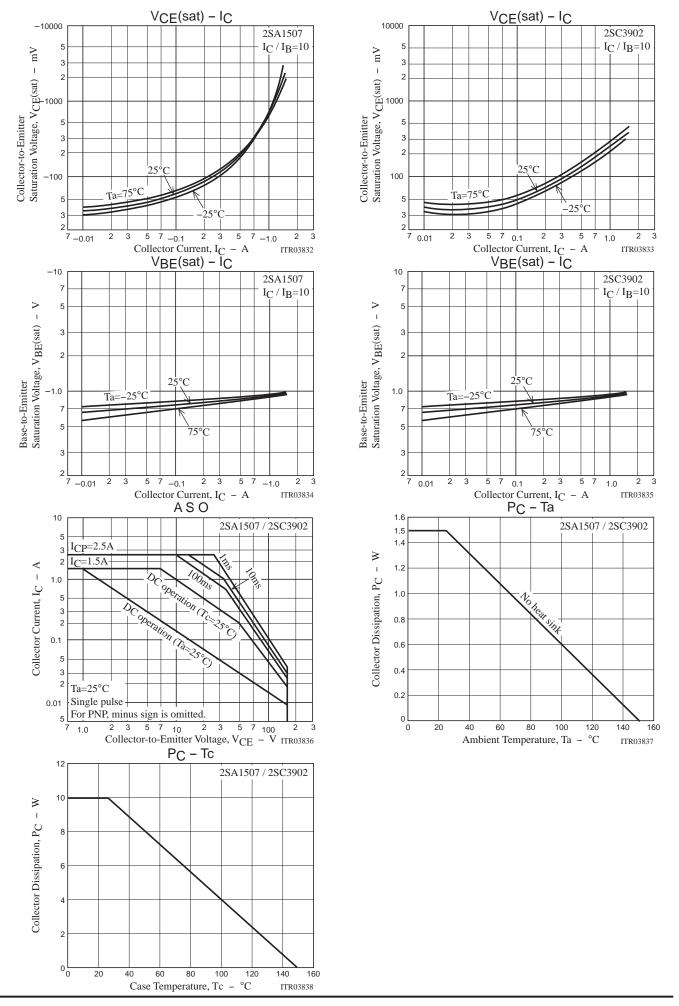
Ordering Information

Device	Package	Shipping	memo
2SA1507S	TO-126ML	200pcs./bag	
2SA1507T	TO-126ML	200pcs./bag	Pb Free
2SC3902S	TO-126ML	200pcs./bag	Pb Flee
2SC3902T	TO-126ML	200pcs./bag	









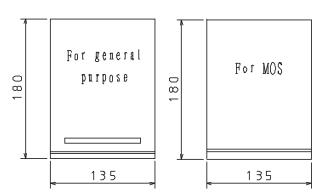
Bag Packing Specification

2SA1507S, 2SA1507T, 2SC3902S, 2SC3902T

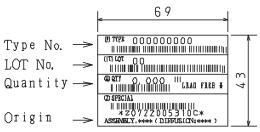
1. Packing Format

Package Name	genjoës contrined (bos) Warjmum Number of			Packing	format
150050 11000	Bag	Inner box	Quier box	Inner BOX	Outer BOX
TO-126ML	200	4,000	12,000	B-1 20 bags contained Dimensions:mm (external) 445×225×55	A-2 3 inner boxes contained Dimensions:mm (external) 470×250×190

2. Bag dimensions (unit;mm)



3. Bag label, [nner box label (unìt:mm)

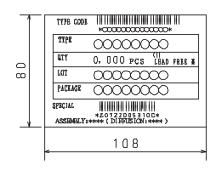


NOTE(1)
The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Labe1		JEITA Phase
LEAD FREE	3	JEITA Phase 3A
LEAD FREE	4	JEITA Phase 3

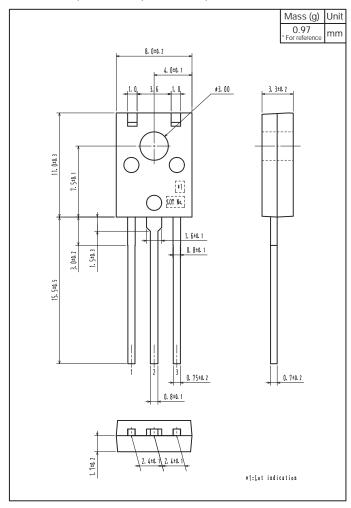
4. Outer box label (unìt:mm)

It is a label at the time of factory shipments, The form of a label may change in physical distribution process.



Outline Drawing

2SA1507S, 2SA1507T, 2SC3902S, 2SC3902T



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